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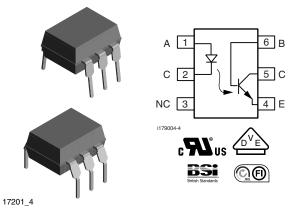




# CNY17., CNY17G

**Vishay Semiconductors** 

### **Optocoupler, Phototransistor Output, with Base Connection**



#### DESCRIPTION

The CNY17 is an optically coupled pair consisting of a gallium arsenide infrared emitting diode optically coupled to a silicon NPN phototransitor.

Signal information, including a DC level, can be transmitted by the device while maintaining a high degree of electrical isolation between input and output.

The CNY17 can be used to replace relays and transformers in many digital interface applications, as well as analog applications such as CRT modulation.

#### FEATURES

- Isolation test voltage 5000 V<sub>RMS</sub>
- · Long term stability
- Industry standard dual-in-line package
- V<sub>IORM</sub> = 850 V
- Material categorization: For definitions of compliance please see www.vishay.com/doc?99912

#### AGENCY APPROVALS

- UL file no. E52744
- cUL tested to CSA 22.2 bulletin 5A
- DIN EN 60747-5-5 (0884-5) available with option 1
- BSI IEC 60950-1:2006 IEC 60065
- FIMKO
- CQC

ORDERING INFORMATION								
	] 1 [	7 -		DIP-6 DIP-6, 400 mil				
	PART NUMBER		₹7.6	32 mm				
AGENCY CERTIFIED/PACKAGE	CTR (%)							
cUL, VDE, BSI, FIMKO, CQC	40 to 80	63 to 125	100 to 200	160 to 320				
DIP-6	CNY17-1.	CNY17-2.	CNY17-3.	CNY17-4.				
DIP-6, 400 mil	CNY17G-1	CNY17G-2	CNY17G-3	CNY17G-4				

<b>ABSOLUTE MAXIMUM RATINGS</b> (T <sub>amb</sub> = 25 °C, unless otherwise specified)							
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT			
INPUT							
Reverse voltage		V <sub>R</sub>	5	V			
Forward current		l <sub>F</sub>	60	mA			
Surge current	t ≤ 10 µs	I <sub>FSM</sub>	3	А			
Power dissipation		P <sub>diss</sub>	100	mW			
OUTPUT							
Collector emitter breakdown voltage		BV <sub>CEO</sub>	70	V			
Emitter base breakdown voltage		BV <sub>EBO</sub>	7	V			
		Ι <sub>C</sub>	50	mA			
Collector current	t < 1 ms	Ι <sub>C</sub>	100	mA			
Power dissipation		P <sub>diss</sub>	150	mW			

Rev. 1.6, 17-Feb-14







## CNY17., CNY17G

### **Vishay Semiconductors**

<b>ABSOLUTE MAXIMUM RATINGS</b> (T <sub>amb</sub> = 25 °C, unless otherwise specified)								
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT				
COUPLER								
Isolation test voltage between emitter and detector referred to climate DIN 50014, part 2, Nov. 74	t = 1 min	V <sub>ISO</sub>	5000	V <sub>RMS</sub>				
Creepage distance (CNY17.)			≥ 7	mm				
Clearance distance (CNY17.)			≥ 7	mm				
Creepage distance (CNY17G)			≥ 8	mm				
Clearance distance (CNY17G)			≥ 8	mm				
Isolation thickness between emitter and detector			≥ 0.4	mm				
Comparative tracking index per DIN IEC 112/VDE 0303, part 1			250					
Isolation resistance	$V_{IO} = 500 \text{ V}, \text{ T}_{amb} = 25 ^{\circ}\text{C}$	R <sub>IO</sub>	≥ 10 <sup>12</sup>	Ω				
Isolation resistance	$V_{IO} = 500 \text{ V}, \text{ T}_{amb} = 100 ^{\circ}\text{C}$	R <sub>IO</sub>	≥ 10 <sup>11</sup>	Ω				
Storage temperature		T <sub>stg</sub>	- 55 to + 125	°C				
Operating temperature		T <sub>amb</sub>	- 55 to + 100	°C				
Soldering temperature <sup>(1)</sup>	max. 10 s, dip soldering: distance to seating plane ≥ 1.5 mm	T <sub>sld</sub>	260	°C				

#### Notes

• Stresses in excess of the absolute maximum ratings can cause permanent damage to the device. Functional operation of the device is not implied at these or any other conditions in excess of those given in the operational sections of this document. Exposure to absolute maximum ratings for extended periods of the time can adversely affect reliability.

<sup>(1)</sup> Refer to wave profile for soldering conditions for through hole devices.

<b>ELECTRICAL CHARACTERISTICS</b> (T <sub>amb</sub> = 25 °C, unless otherwise specified)								
PARAMETER	TEST CONDITION	PART	SYMBOL	MIN.	TYP.	MAX.	UNIT	
INPUT								
Forward voltage	I <sub>F</sub> = 60 mA		V <sub>F</sub>		1.25	1.65	V	
Breakdown voltage	I <sub>R</sub> = 10 μA		V <sub>BR</sub>	6			V	
Reverse current	V <sub>R</sub> = 6 V		I <sub>R</sub>		0.01	10	μA	
Capacitance	V <sub>R</sub> = 0 V, f = 1 MHz		Co		25		pF	
Thermal resistance			R <sub>th</sub>		750		K/W	
OUTPUT						•		
Collector emitter capacitance	V <sub>CE</sub> = 5 V, f = 1 MHz		C <sub>CE</sub>		5.2		pF	
Collector base capacitance	V <sub>CB</sub> = 5 V, f = 1 MHz		C <sub>CB</sub>		6.5		pF	
Emitter base capacitance	V <sub>EB</sub> = 5 V, f = 1 MHz		C <sub>EB</sub>		7.5		pF	
Thermal resistance			R <sub>th</sub>		500		K/W	
COUPLER								
Collector emitter, saturation voltage	$I_F = 10 \text{ mA}, I_C = 2.5 \text{ mA}$		V <sub>CEsat</sub>		0.25	0.4	V	
Coupling capacitance			C <sub>C</sub>		0.6		pF	
		CNY17-1	I <sub>CEO</sub>		2	50	nA	
	V 10.V	CNY17-2	I <sub>CEO</sub>		2	50	nA	
Collector emitter, leakage current	V <sub>CE</sub> = 10 V	CNY17-3	I <sub>CEO</sub>		5	100	nA	
		CNY17-4	I <sub>CEO</sub>		5	100	nA	

#### Note

• Minimum and maximum values were tested requierements. Typical values are characteristics of the device and are the result of engineering evaluations. Typical values are for information only and are not part of the testing requirements.

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### CNY17., CNY17G

### Vishay Semiconductors

CURRENT TRANSFER RATIO								
PARAMETER	TEST CONDITION	PART	SYMBOL	MIN.	TYP.	MAX.	UNIT	
	V <sub>CE</sub> = 5 V, I <sub>F</sub> = 10 mA	CNY17-1	CTR	40		80	%	
		CNY17-2	CTR	63		125	%	
		CNY17-3	CTR	100		200	%	
1- /1-		CNY17-4	CTR	160		320	%	
I <sub>C</sub> /I <sub>F</sub>		CNY17-1	CTR	13	30		%	
	$V_{-} = 5 V_{-} = 1 m \Lambda$	CNY17-2	CTR	22	45		%	
	$V_{CE} = 5 V, I_F = 1 mA$	CNY17-3	CTR	34	70		%	
		CNY17-4	CTR	56	90		%	

Note

• Current transfer ratio and collector-emitter leakage current by dash number (Tamb °C).

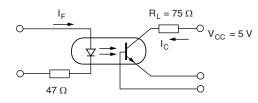
SWITCHING CHAR	ACTERISTICS (T <sub>amb</sub> = 25 °C, unles	s otherwise	e specified	)			
PARAMETER	TEST CONDITION	PART	SYMBOL	MIN.	TYP.	MAX.	UNIT
LINEAR OPERATION (WI	THOUT SATURATION)				•	•	•
Turn-on time	$I_F$ = 10 mA, $V_{CC}$ = 5 V, $R_L$ = 75 $\Omega$		t <sub>on</sub>		3		μs
Rise time	$I_F$ = 10 mA, $V_{CC}$ = 5 V, $R_L$ = 75 $\Omega$		t <sub>r</sub>		2		μs
Turn-off time	$I_F$ = 10 mA, $V_{CC}$ = 5 V, $R_L$ = 75 $\Omega$		t <sub>off</sub>		2.3		μs
Fall time	$I_F$ = 10 mA, $V_{CC}$ = 5 V, $R_L$ = 75 $\Omega$		t <sub>f</sub>		2		μs
Cut-off frequency	$I_F$ = 10 mA, $V_{CC}$ = 5 V, $R_L$ = 75 $\Omega$		f <sub>CO</sub>		250		kHz
SWITCHING OPERATION	(WITH SATURATION)						
	I <sub>F</sub> = 20 mA	CNY17-1	t <sub>on</sub>		3		μs
Turne and time a	10 10 10	CNY17-2	t <sub>on</sub>		4.2		μs
Turn-on time	I <sub>F</sub> = 10 mA	CNY17-3	t <sub>on</sub>		4.2		μs
	I <sub>F</sub> = 5 mA	CNY17-4	t <sub>on</sub>		6		μs
	I <sub>F</sub> = 20 mA	CNY17-1	t <sub>r</sub>		2		μs
Rise time	1. 10 mA	CNY17-2	t <sub>r</sub>		3		μs
Rise lime	I <sub>F</sub> = 10 mA	CNY17-3	t <sub>r</sub>		3		μs
	I <sub>F</sub> = 5 mA	CNY17-4	t <sub>r</sub>		4.6		μs
	I <sub>F</sub> = 20 mA	CNY17-1	t <sub>off</sub>		18	MAX.	μs
Tunn off times	10 10 10	CNY17-2	t <sub>off</sub>		23		μs
Turn-off time	I <sub>F</sub> = 10 mA	CNY17-3	t <sub>off</sub>		23		μs
	I <sub>F</sub> = 5 mA	CNY17-4	t <sub>off</sub>		25		μs
	I <sub>F</sub> = 20 mA	CNY17-1	t <sub>f</sub>		11		μs
Call time	10 - 10 10	CNY17-2	t <sub>f</sub>		14		μs
Fall time	I <sub>F</sub> = 10 mA	CNY17-3 t <sub>f</sub>			14		μs
	I <sub>F</sub> = 5 mA	CNY17-4	t <sub>f</sub>		15		μs



### CNY17., CNY17G

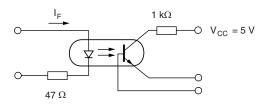
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#### TYPICAL CHARACTERISTICS (T<sub>amb</sub> = 25 °C, unless otherwise specified)



icny17\_01





icny17\_02

#### Fig. 1 - Switching Operation (with Saturation)

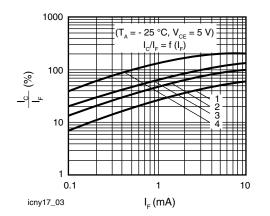


Fig. 2 - Current Transfer Ratio vs. Diode Current

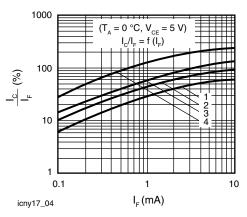


Fig. 3 - Current Transfer Ratio vs. Diode Current

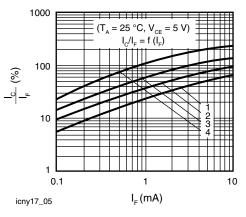


Fig. 4 - Current Transfer Ratio vs. Diode Current

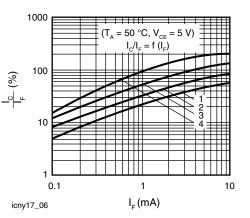


Fig. 5 - Current Transfer Ratio vs. Diode Current

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CNY17., CNY17G

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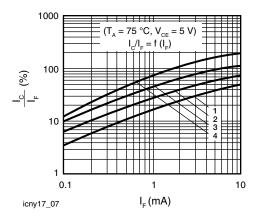


Fig. 6 - Current Transfer Ratio vs. Diode Current

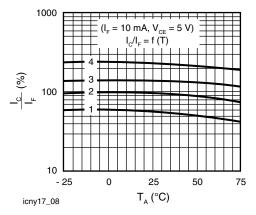


Fig. 7 - Current Transfer Ratio (CTR) vs. Temperature

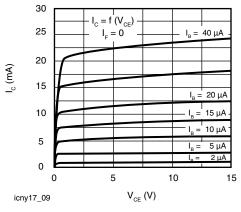


Fig. 8 - Transistor Characteristics

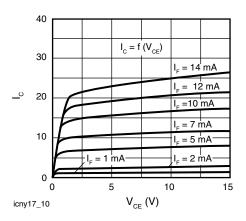


Fig. 9 - Output Characteristics

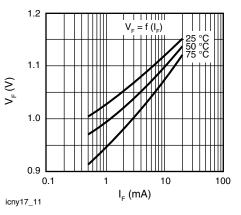


Fig. 10 - Forward Voltage vs. Forward Current

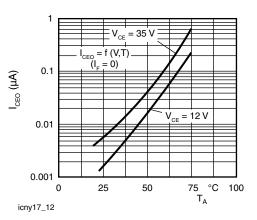
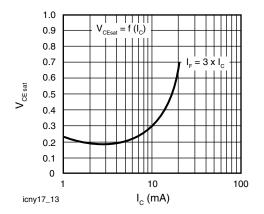
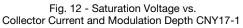


Fig. 11 - Leakage Current vs. Ambient Temperature

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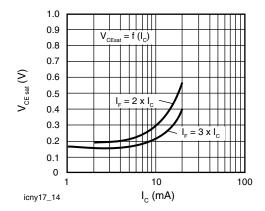
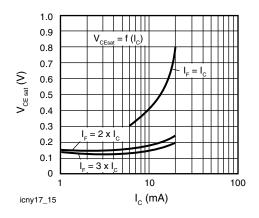
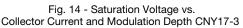
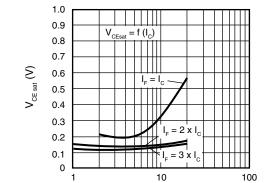


Fig. 13 - Saturation Voltage vs. Collector Current and Modulation Depth CNY17-2







**CNY17., CNY17G** 

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Fig. 15 - Saturation Voltage vs. Collector Current and Modulation Depth CNY17-4

icny17\_16

I<sub>c</sub> (mA)

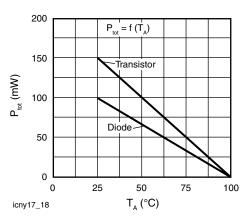


Fig. 16 - Permissible Power Dissipation for Transistor and Diode

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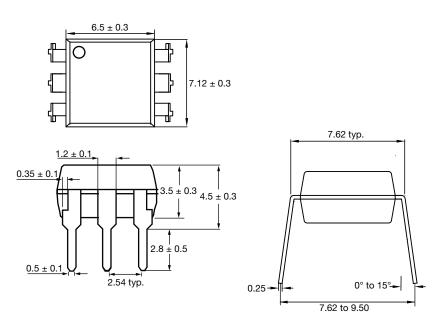


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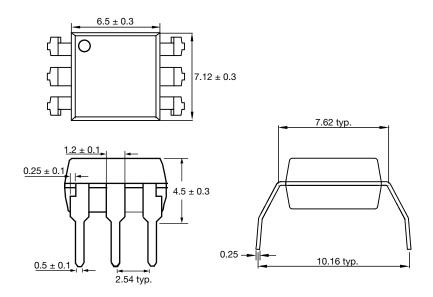
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#### **PACKAGE DIMENSIONS** in millimeters

DIP-6



DIP-6, 400 mil



#### **PACKAGE MARKING**



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